TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

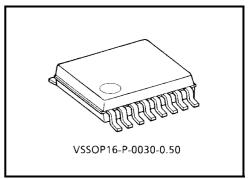
TC7MH367FK,TC7MH368FK

HEX Bus Buffer TC7MH367FK Non-Inverted, 3-State Outputs TC7MH368FK Inverted, 3-State Outputs

The TC7MH367FK and TC7MH368FK are advanced high speed CMOS HEX bus buffers fabricated with silicon gate $\rm C^2MOS$ technology.

They achieve the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

They contain six buffers; four buffers are controlled by an enable input ($\overline{G}1$), and the other two buffers are controlled by another enable input ($\overline{G}2$). The outputs of each buffer group are enabled when $\overline{G}1$ and/or $\overline{G}2$ inputs are held low; if held high, these outputs are in a high impedance state.



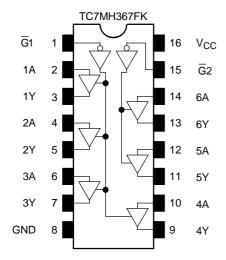
Weight: 0.02 g (typ.)

The TC7MH367FK is a non-inverting output type, while the TC7MH368FK is an inverting output type. An input protection circuit ensures that 0 to 7 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

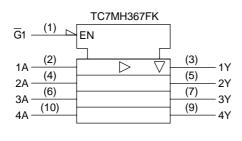
Features

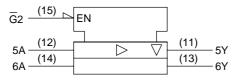
- High speed: $t_{pd} = 3.8 \text{ ns} (typ.) (V_{CC} = 5 \text{ V})$
- Low power dissipation: $ICC = 4 \mu A (max) (Ta = 25^{\circ}C)$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH}\approx t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2~5.5 V
- Low noise: VOLP = 0.8 V (max)
- Pin and function compatible with 74ALS367/368

Pin Assignment (top view)







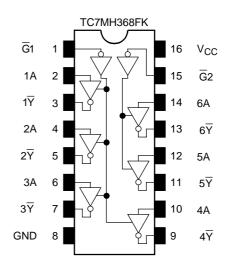


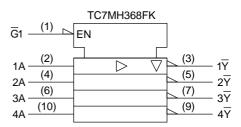
Truth Table

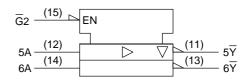
Inp	uts	Outputs				
G	А	Y (367)	- <u>Y</u> (368)			
L	L	L	Н			
L	Н	Н	L			
Н	Х	Z	Z			

X: Don't care

Z: High impedance







Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7.0	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	Vout	$-0.5 \sim V_{CC} + 0.5$	V
Input diode current	IIK	-20	mA
Output diode current	I _{OK}	±20	mA
DC output current	IOUT	±25	mA
DC V _{CC} /ground current	ICC	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65~150	°C

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0~5.5	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V _{OUT}	0~V _{CC}	V	
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	0~100 (V_{CC} = 3.3 \pm 0.3 V)	ns/V	
input lise and fair time	uvuv	0~20 (V_{CC} = 5 \pm 0.5 V)	113/ V	

Electrical Characteristics

DC Characteristics

Characteristics Symbol Test Condition		Symbol	Symbol Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
		$V_{CC}(V)$	Min	Тур.	Max	Min	Max	Unit			
High level			_		2.0	1.50			1.50	_	v
	High level	VIH			3.0~5.5	$\begin{array}{c} V_{CC} \\ \times \ 0.7 \end{array}$	_	_	$V_{CC} \times 0.7$	_	
input voltage					2.0		_	0.50	_	0.50	v
	Low level	VIL		—			_	$V_{CC} \times 0.3$	_	$V_{CC} \times 0.3$	
				I _{OH} = -50 μA	2.0	1.9	2.0	—	1.9	_	
			V _{IN} = V _{IH} or V _{IL}		3.0	2.9	3.0		2.9	_	
Putput voltage	High level	V _{OH}			4.5	4.4	4.5		4.4	—	
				$I_{OH} = -4 \text{ mA}$	3.0	2.58	_	_	2.48	—	
				$I_{OH} = -8 \text{ mA}$	4.5	3.94	_	_	3.80	—	V
Output voltage			V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0	0.1	_	0.1	
		ow level V _{OL}			3.0	_	0	0.1	—	0.1	
	Low level				4.5	_	0	0.1		0.1	
				$I_{OL} = 4 \text{ mA}$	3.0	_	—	0.36		0.44	
				$I_{OL} = 8 \text{ mA}$	4.5	_	—	0.36	—	0.44	
3-state output of	f-state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		5.5	_	—	±0.25	_	±2.50	μΑ
Input leakage cu	irrent	I _{IN}	$V_{IN} = 5.5 \text{ V or GND}$		0~5.5			±0.1		±1.0	μA
Quiescent suppl	y current	ICC	$V_{IN} = V_{CC}$ or GND		5.5			4.0	_	40.0	μA

AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Oh and a tariation	Symbol Test Condition				Ta = 25°C			Ta = -40~85°C		Unit
Characteristics	Symbol	lest Condition	$V_{CC}(V)$	C _L (pF)	Min	Тур.	Max	Min	Max	Unit
		t _{pLH}	3.3 ± 0.3 -	15	_	5.9	8.3	1.0	10.0	ns
Propagation delay time	t _{pLH}			50	_	8.4	11.8	1.0	13.5	
(TC7MH367)	t _{pHL}		5.0 ± 0.5	15	_	4.1	5.9	1.0	7.0	
			5.0 ± 0.5	50	_	5.6	7.9	1.0	9.0	
			3.3 ± 0.3	15		5.3	7.5	1.0	9.0	
Propagation delay time	t _{pLH}		5.5 ± 0.5	50	_	7.8	11.0	1.0	12.5	ns.
(TC7MH368)	t _{pHL}		5.0 ± 0.5	15	_	3.8	5.5	1.0	6.5	
				50	_	5.3	7.5	1.0	8.5	
	t _{pZL} t _{pZH}	$R_L = 1 \ k\Omega$	$\begin{array}{c} 3.3\pm0.3\\ \\ 5.0\pm0.5\end{array}$	15	_	6.8	10.5	1.0	12.5	ns
3-state output enable time				50	_	9.3	14.0	1.0	16.0	
5-State Output enable time				15	_	4.8	7.2	1.0	8.5	
				50	_	6.3	9.2	1.0	10.5	
3-state output disable time	t _{pLZ}	$R_L = 1 k\Omega$	$\textbf{3.3}\pm\textbf{0.3}$	50	_	9.9	13.6	1.0	15.5	ns
5-state output disable time	t _{pHZ}		5.0 ± 0.5	50	_	6.3	9.2	1.0	10.5	115
Output to output skew	t _{osLH}	(Note1)	$\textbf{3.3}\pm\textbf{0.3}$	50	_	_	1.5	_	1.5	ns
	t _{osHL}	(NOTE I)	5.0 ± 0.5	50		_	1.0		1.0	115
Input capacitance	C _{IN}	-				4	10	_	10	pF
Output capacitance	C _{OUT}	-	_			6	_			pF
Power dissipation capacitance	C _{PD}			(Note2)	_	19		_	—	pF

Note1: Parameter guaranteed by design.

 $t_{OSLH} = |t_{pLHm} - t_{pLHn}|, \ t_{OSHL} = |t_{pHLm} - t_{pHLn}|$

Note2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

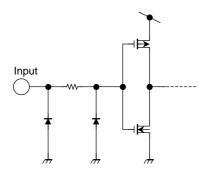
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6$ (per bit)

Noise Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	_	Ta = 25°C		Unit
Characteristics	Symbol	Test Condition	$V_{CC}(V)$	Тур.	Limit	Unit
Quiet output maximum dynamic V_{OL}	V _{OLP}	C _L = 50 pF	5.0	0.4	0.8	V
Quiet output minimum dymnamic V_{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.4	-0.8	V
Minimum high level dynamic input voltage V_{IH}	V _{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage V_{IL}	V _{ILD}	C _L = 50 pF	5.0		1.5	V

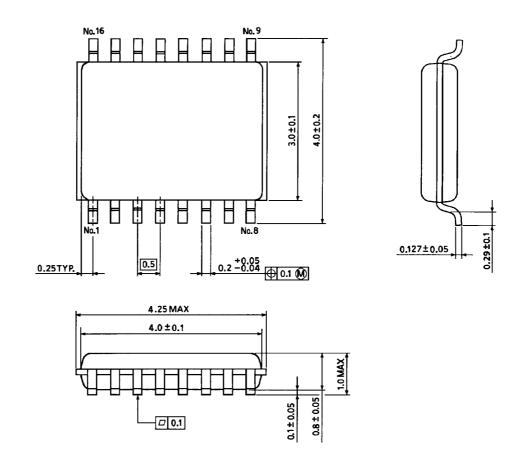
Input Equivalent Circuit



Package Dimensions

VSSOP16-P-0030-0.50

Unit : mm



Weight: 0.02 g (typ.)

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